Atty. Dkt. No. THORSANS

IN THE CLAIMS:

- A method of fabricating a radiation detector array (Previously Presented) 1. comprising the steps of:
 - providing on one face of a layer of material, an array of detector a) elements each including a material which absorbs the radiation;
- forming an array of cavities in the layer of material such that each detector b) is positioned at the base only of a cavity, the cavities having reflective walls for reflecting radiation onto the detectors; and
 - bonding the array of cavities and detectors to a silicon integrated circuit including a corresponding array of amplifiers and multiplex switches.
- A method as claimed in claim 1 in which the layer of material is a 2. (Original) silicon wafer and the cavities are formed by etching the wafer.
- A method as claimed in claim 2, in which the etching process is 3. (Original) deep reactive ion etching.
- A method as claimed in claim 1 in which a profiled polymer mask is 4. (Original) used to define the array of cavities.
- A method as claimed in claim 1 comprising the further step of at 5. (Original) least partially coating the cavities with metal.
- A method as claimed in claim 5, in which the metal is sputtered 6. (Original) onto the cavities.
- A method as claimed in claim 5, in which the metal is evaporated 7. (Original) onto the cavities.

- 8. (Original) A method as claimed in claim 1 including the further step of wholly or partially filling the cavities with dielectric material of refractive index higher than air.
- 9. (Previously Presented) A method of fabricating a radiation detector **array** comprising the steps of:
- a) forming in a layer of material an array of cavities having walls which reflect the radiation towards the bases of the cavities;
- b) providing, on one face of the material, an array of detector elements, each including a material which absorbs the radiation, such that one element is positioned at the base only of each cavity; and
- c) bonding the array of cavities and detectors to a silicon integrated circuit including a corresponding array of amplifiers and multiplex switches.
- 10. (Original) A method as claimed in claim 9 in which the layer of material is a silicon wafer and the cavities are formed by etching the wafer.
- 11. (Original) A method as claimed in claim 10, in which the etching process is deep reactive ion etching.
- 12. (Original) A method as claimed in claim 9 in which a profiled polymer mask is used to define the array of cavities.
- 13. (Original) A method as claimed in claim 9 comprising the further step of at least partially coating the cavities with metal.
- 14. (Original) A method as claimed in claim 13, in which the metal is sputtered onto the cavities.
- 15. (Original) A method as claimed in claim 13, in which the metal is evaporated onto the cavities.

- 16. (Original) A method as claimed in claim 9 including the further step of wholly or partially filling the cavities with dielectric material of refractive index higher than air.
- 17. (Previously Presented) A radiation detector array comprising an array of radiation collector cavities formed in a layer of material, the cavities having walls which reflect the radiation; and an array of detector elements on one face of the layer of material arranged with an element at the base only of each cavity, the elements including a material which absorbs the radiation; wherein the array of cavities and detectors is bonded to a silicon integrated circuit including a corresponding array of amplifiers and multiplex switches.
- 18. (Original) An array as claimed in claim 17, in which the detector elements are infrared detector elements.
- 19. (Original) An array as claimed in claim 17 in which the cavities are shaped so as to have a gradually reducing cross sectional area from their openings towards their bases.
- 20. (Original) An array as claimed in claim 19, in which the cavities are conical.
- 21. (Original) An array as claimed in claim 19, in which the inner surfaces of the cavities are parabolic in shape.
- 22. (Original) An array as claimed in claim 21, in which the detectors are positioned at the foci of the parabolas.
- 23. (Original) An array as claimed in claim 17 wherein the pyroelectric detectors are made from a thin film of a material that is substantially lead zirconate titanate.
- 24. (Original) An array as claimed in claim 17 wherein the detectors are made from a thin film of a material that is substantially lead scandium tantalite.

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- (Original) An array as claimed in claim 17 wherein the detectors are made 25. from a thin film of a material that is substantially a copolymer of polyvinylidene fluoride and trifluoroethylene.
- 26. An array as claimed in claim 17, wherein the array is bonded using (Original) conductive bumps are made of silver loaded epoxy.
- 27. An array as claimed in claim 17 wherein the array is bonded using (Original) conductive bumps made of solder.
- 28. (Original) An array as claimed in claim 17 wherein the array is bonding using conductive bumps made of electroplated gold.
- 29. An array as claimed in claim 17, wherein the cavities are at least (Original) partially coated with metal.
- An array as claimed in claim 17 wherein the cavities are each 30. (Original) provided with a lens to improve the angular collection efficiency.
- 31. (Original) An array as claimed in claim 17 wherein the cavities are wholly or partially filled with a dielectric material of higher refractive index than air.
- 32. (Original) An array as claimed in claim 30 wherein the cavities are wholly or partially filled with a dielectric material of higher refractive index than air and the material wholly or partially filling the cavities is the same as the lens material.
- 33. (Original) An array as claimed in claim 17 wherein the detector elements are each provided with a thin film absorber.

- 34. (Original) An array as claimed in claim 17, wherein the absorber comprises a thin film of silicon dioxide coated with a thin layer of metal.
- 35. (Original) An array as claimed in claim 1 in which the detector elements are pyroelectric detector elements.